

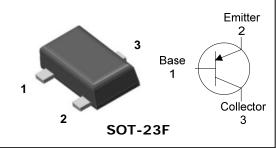
PNP Silicon Transistor

Features

- Extremely low collector-to-emitter saturation voltage
- $(V_{CE(SAT)} = -0.25V \text{ Typ. } @I_C/I_B = -400\text{mA}/-20\text{mA})$
- Suitable for low voltage large current drivers
- Complementary pair with DN100S
- Switching Application

Ordering Information

PIN Connection



Type NO.	Marking	Package Code
DP100S	<u>PO3</u> □ ① ②	SOT-23F

①Device Code ② Year&Week Code

Absolute maximum ratings

Absolute maximum ratings			(Ta=25°C)
Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V _{CBO}	-15	V
Collector-Emitter voltage	V _{CEO}	-12	V
Emitter-Base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-1	А
Collector dissipation	P _C	200	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55~150	°C

Flactrical Characteristics

Liectrical Characteristics (1a=25°C					=25°C)	
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV_{CBO}	I_{C} =-50 μ A, I_{E} =0	-15	-	-	V
Collector-Emitter breakdown voltage	BV _{CEO}	I_{C} =-1mA, I_{B} =0	-12	-	-	V
Emitter-Base breakdown voltage	BV_{EBO}	I_{E} =-50µA, I_{C} =0	-5	-	-	V
Collector cut-off current	I _{CBO}	V_{CB} =-12V, I _E =0	-	-	-0.1	μΑ
Emitter cut-off current	I _{EBO}	V_{EB} =-5V, I_{C} =0	-	-	-0.1	μΑ
DC surrent gain	h _{FE1}	V_{CE} =-1V, I_{C} =-100mA	200	-	450	-
DC current gain	h _{FE2}	V_{CE} =-1V, I_C =-1A	70	-	-	-
Collector-Emitter saturation voltage	V _{CE(sat)}	I_{C} =-400mA, I_{B} =-20mA	-	-	-0.3	V
Base-Emitter saturation voltage	$V_{BE(sat)}$	I_{C} =-400mA, I_{B} =-20mA	-	-	-1.2	V
Transition frequency	f⊤	V_{CE} =-5V, I_{C} =-50mA	-	330	-	MHz
Collector output capacitance	C _{ob}	V_{CB} =-10V, I_E =0, f=1MHz	-	9	-	рF

 (T_{-})

Electrical Characteristic Curves



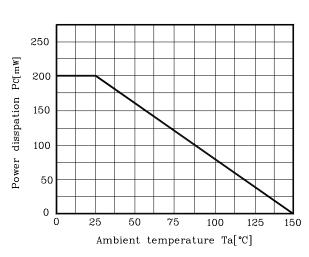


Fig. 3 h_{FE}.I_C

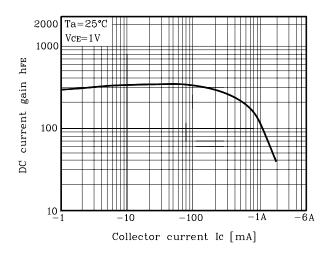


Fig. 2 I_C - V_{BE}

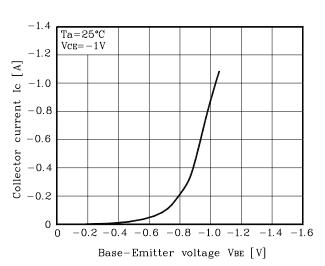
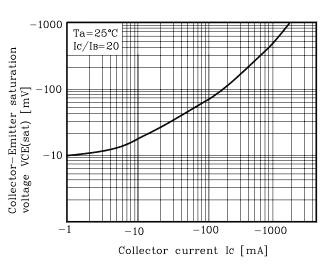
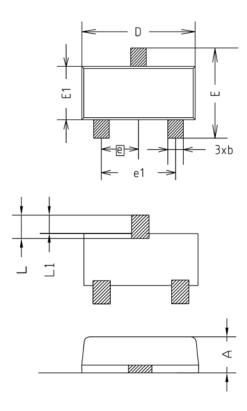
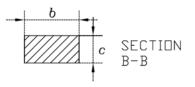


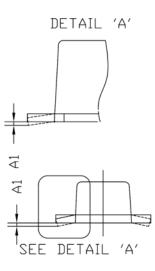
Fig. 4 V_{CE(sat)}-I_C



Outline Dimension

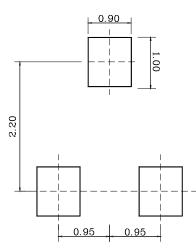






SYMBOL	MILLIMETER(mm)			NOTE	
UNDEL	MINIMUM	NOMINAL	MAXIMUM	NUTE	
A	0.80	0.90	1.00		
A1	0.00	-	0.10		
b	0.35	0.40	0.45		
С	0.10	0.15	0.20		
D	2.80	2.90	3.00		
E	2.30	2.40	2.50		
E1	1.50	1.60	1.70		
e	0.95BSC				
e1	1.80	1.90	2.00		
L	0.48	0.58	0.68		
L1	0.30	-	0.50		

*Recommend PCB solder land [Unit: mm]



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